

Technical Data Sheet

High Power Infrared LED

EAIST3535A3

Features

- Small package with high efficiency
- Peak wavelength $\lambda_p = 940$ nm
- Soldering methods: SMT
- Thermal resistance (junction to lead): 18K/W.
- Pb free
- Compliance with EU REACH
- Compliance Halogen Free (Br < 900ppm, Cl < 900ppm, Br+Cl < 1500ppm)
- The product itself will remain within RoHS compliant version.

Description

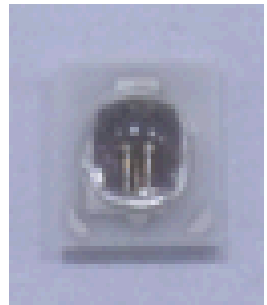
- EAIST3535A3 series is an infrared emitting diode in miniature SMD package which is molded in a water clear silicone with spherical top view lens.
- The device is spectrally matched with silicon photo diode, Phototransistor.

Applications

- CCD Camera
- Infrared applied system

Device Selection Guide

LED Part No.	Chip Material	Lens Color
EAIST3535A3	GaAlAs	Water clear



Absolute Maximum Ratings ($T_A=25^{\circ}\text{C}$)

Parameter	Symbol	Rating	Unit
Continuous Forward Current	I_F	1000	mA
Peak Forward Current *1	I_{FP}	1200	mA
Reverse Voltage	V_R	5	V
Operating Temperature	T_{opr}	-40~ +85	$^{\circ}\text{C}$
Storage Temperature	T_{stg}	-40 ~ +100	$^{\circ}\text{C}$
Junction temperature	T_j	115	$^{\circ}\text{C}$
Thermal resistance (junction to lead frame)	$R_{th(j-L)}$	18	K /W
Power Dissipation @ $I_F=700\text{mA}$	P_d	1	W

Notes:

*1. I_{FP} Conditions--Pulse Width $\leq 100\mu\text{s}$ and Duty $\leq 1\%$

*2. Note: We suggest that customer should add the heat sink with EAIST3535A3 to exclude the heat.

Electro-Optical Characteristics ($T_A=25^{\circ}\text{C}$)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition
Total Radiated Power	P_o	200	235	--	mW	$I_F=350\text{ mA}$
		400	465	--		$I_F=700\text{ mA}$
		600	660	--		$I_F=1\text{ A}$
Radiant Intensity	I_E	40	75	--	mW/sr	$I_F=350\text{ mA}$
		100	155	--		$I_F=700\text{ mA}$
		160	220	--		$I_F=1\text{ A}$
Peak Wavelength	λ_P	925	940	955	nm	$I_F=350\text{ mA}$
Spectral Bandwidth	$\Delta\lambda$	--	30	--	nm	$I_F=350\text{ mA}$
Forward Voltage	V_F	--	1.60	1.90	V	$I_F=350\text{ mA}$
		--	1.90	2.20		$I_F=700\text{ mA}$
		--	2.10	2.40		$I_F=1\text{ A}$
Reverse Current	I_R	--	--	10	μA	$V_R=5\text{ V}$
View Angle	$2\theta_{1/2}$	--	105	--	deg	$I_F=20\text{ mA}$

Notes:

*3. I_{FP} Conditions--Pulse Width $\leq 100\mu\text{s}$ and Duty $\leq 1\%$

Typical Electro-Optical Characteristics Curves

Fig.1

Forward Current vs. Ambient Temperature

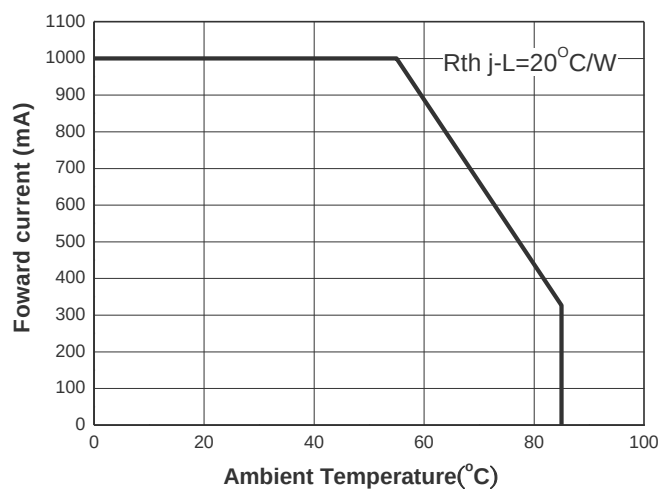


Fig.2

Spectral Distribution

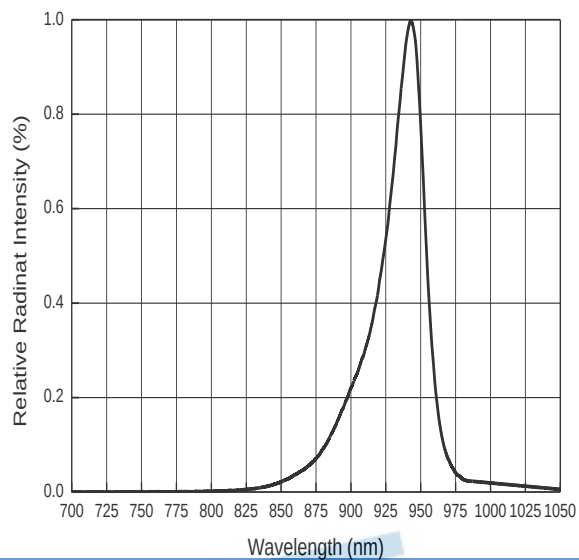


Fig.3

Forward Current vs. Total Power

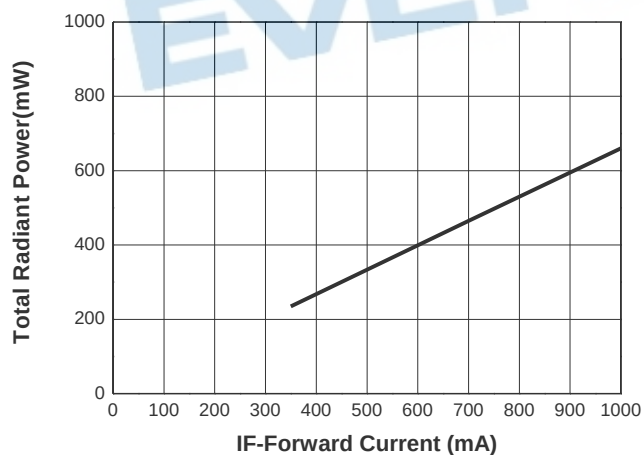
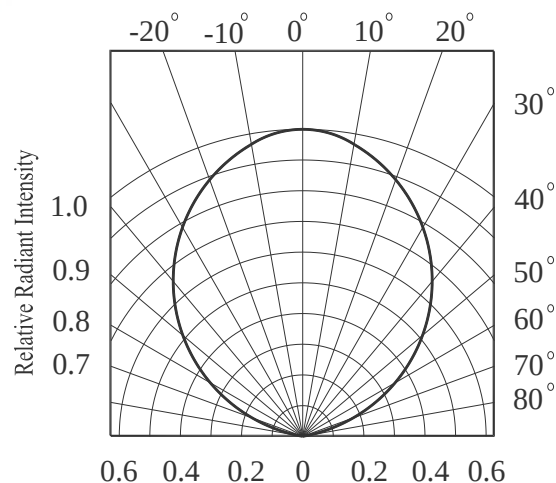
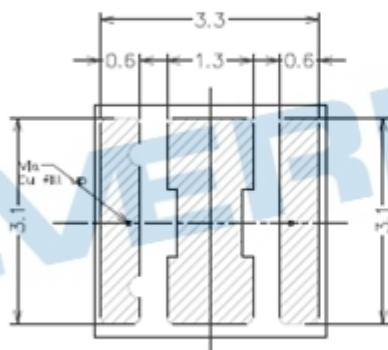
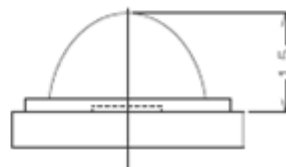
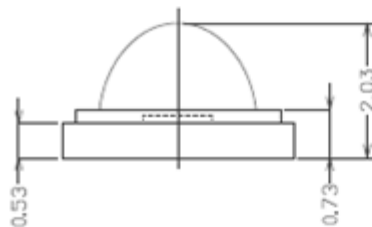
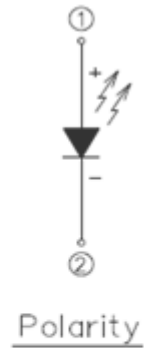
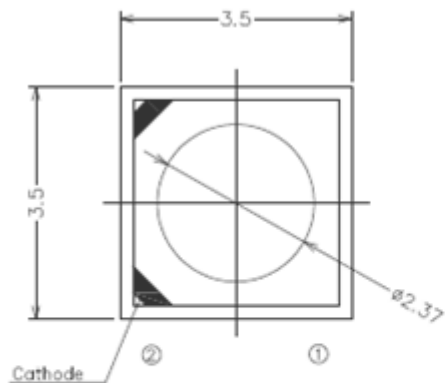


Fig.4

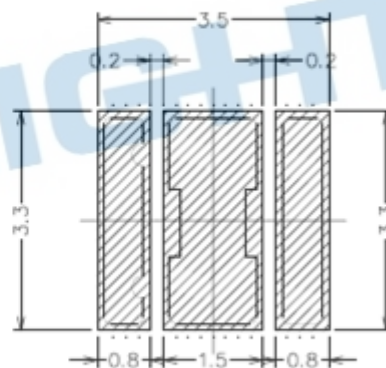
Relative Radiant Intensity vs. Angular Displacement



Package Dimension



Solder pad design

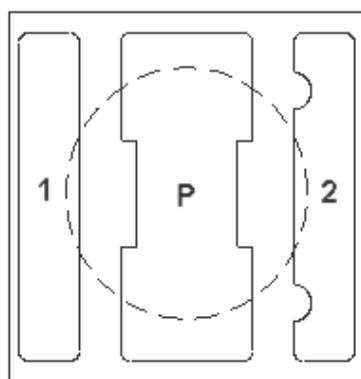


Soldering patterns

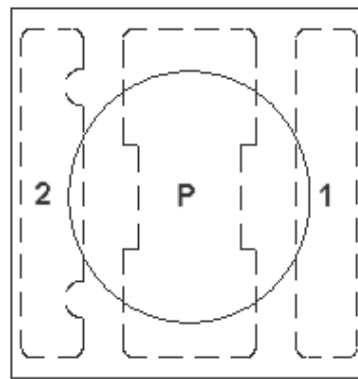
1. Dimensions are in millimeters.
2. Tolerances unless mentioned are $\pm 0.1\text{mm}$.
3. Do not handle the device by the lens. Incorrect force applied to the lens may lead to the failure of devices.

Pad Configuration

Pad	1	2	P
Function	Anode	Cathode	Thermal Pad



BOTTOM VIEW



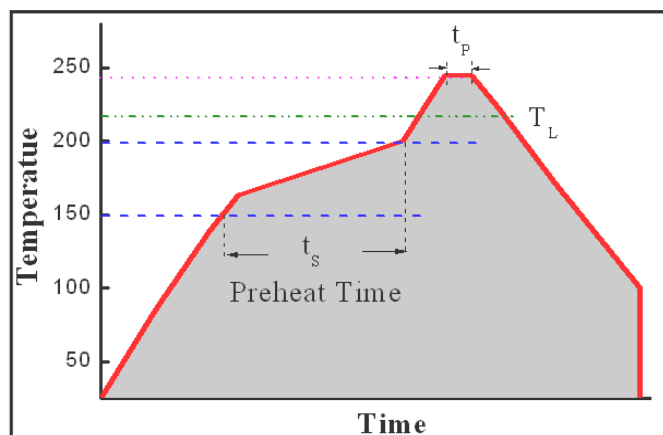
TOP VIEW

Reflow Soldering Characteristics

For Reflow Process

1. C19 series are suitable for SMT processes.
2. Curing of glue in oven must be according to standard operation flow processes.

Profile Feature	Lead Free Assembly	Unit
Ramp-Up Rate	2~3	°C/S
Preheat Temperature	150~200	°C
Preheat Time(t_s)	60~120	S
Liquid Temperature(T_L)	217	°C
Time maintained above T_L	60~90	S
Peak Temperature(T_P)	240 $\pm$ 5	°C
Peak Time (t_p)	Max 20	S
Ramp-Down Rate	3~5	°C/S



3. Reflow soldering should not be done more than twice.
4. In soldering process, stress on the LEDs during heating should be avoided.
5. After soldering, do not bend the circuit board.

Technical drawing of a circular mechanical part. The drawing includes a top view and a side view.

Top View Dimensions:

- Central hole diameter: $\varnothing 13.0 \pm 0.20$
- Keyway width: 2.5 ± 0.50
- Outer diameter: $\varnothing 180 \pm 2.0$

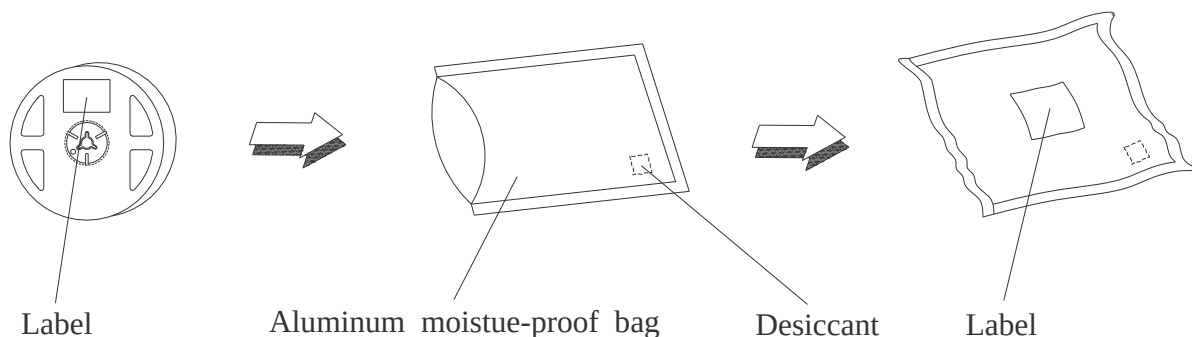
Side View Dimensions:

- Overall height: 15.4 ± 1.0
- Internal feature height: $13.0 + 0.3, -0.0$

[illegible]

www.everlight.com

Moisture Resistant Packaging



Moisture Resistant Packing Materials

Label Form Specification

RoHS  EVERLIGHT	
CPN : XXXXXXXXXX-XXXXXXXXXX-XXXXXXXXXX-XXXXXXXXXX-XXXXXX	
P/N : XXXXXXXXXX-XXXXXXXXXX-XXXXXXXXXX-XXXXXXXXXX-XXXXXX	
LOT NO : XXXXXXXXXX-XXXXXXXXXX-XXXXXXXXXX-XXXXXXXXXX-XXXXXX	
QTY :	HUE :
CAT :	REF :
REFERENCE :	



- CPN: Customer's Product Number
- P/N: Product Number
- QTY: Packing Quantity
- CAT: Luminous Intensity Rank
- HUE: Dom. Wavelength Rank
- REF: Forward Voltage Rank
- LOT No: Lot Number
- X: Month
- Reference: Identify Label Number

EVERLIGHT ELECTRONICS CO., LTD.

Office: No 6-8, Zhonghua Rd., Shulin Dist.,

Tel: 886-2-2685-6688

Fax: 886-2-2685-6897

DISCLAIMER

1. EVERLIGHT reserves the right(s) on the adjustment of product material mix for the specification.
2. The product meets EVERLIGHT published specification for a period of twelve (12) months from date of shipment.
3. The graphs shown in this datasheet are representing typical data only and do not show guaranteed values.
4. When using this product, please observe the absolute maximum ratings and the instructions for using outlined in these specification sheets. EVERLIGHT assumes no responsibility for any damage resulting from the use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.
5. These specification sheets include materials protected under copyright of EVERLIGHT. Reproduction in any form is prohibited without obtaining EVERLIGHT's prior consent.
6. This product is not intended to be used for military, aircraft, automotive, medical, life sustaining or life saving applications or any other application which can result in human injury or death. Please contact authorized Everlight sales agent for special application request.